1. Record Nr. UNINA9910826277403321 Autore Arrillaga J Titolo Self-commutating converters for high power applications / / Jos Arrillaga ... [et al.] Chichester, West Sussex, U.K., : J. Wiley, 2009 Pubbl/distr/stampa **ISBN** 1-282-69002-7 9786612690020 0-470-68211-6 0-470-68212-4 Edizione [1st ed.] Descrizione fisica 1 online resource (326 p.) 621.31/7 Disciplina Soggetti Commutation (Electricity) Electric current converters Electric power distribution - High tension Lingua di pubblicazione Inglese **Formato** Materiale a stampa Livello bibliografico Monografia Note generali Description based upon print version of record. Includes bibliographical references and index. Nota di bibliografia Nota di contenuto Self-Commutating Converters for High Power Applications; Contents: Preface; 1 Introduction; 1.1 Early developments; 1.2 State of the large power semiconductor technology; 1.2.1 Power ratings; 1.2.2 Losses; 1.2.3 Suitability for large power conversion: 1.2.4 Future developments: 1.3 Voltage and current source conversion; 1.4 The pulse and level number concepts; 1.5 Line-commutated conversion (LCC); 1.6 Selfcommutating conversion (SCC); 1.6.1 Pulse width modulation (PWM); 1.6.2 Multilevel voltage source conversion; 1.6.3 High-current selfcommutating conversion; 1.7 Concluding statement References 2 Principles of Self-Commutating Conversion; 2.1 Introduction; 2.2 Basic VSC operation; 2.2.1 Power transfer control; 2.3 Main converter components; 2.3.1 DC capacitor; 2.3.2 Coupling reactance; 2.3.3 The high-voltage valve; 2.3.4 The anti-parallel diodes; 2.4 Three-phase voltage source conversion; 2.4.1 The six-pulse VSC configuration; 2.4.2 Twelve-pulse VSC configuration; 2.5 Gate driving signal generation; 2.5.1 General philosophy; 2.5.2 Selected harmonic

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Sommario/riassunto

For very high voltage or very high current applications, the power industry still relies on thyristor-based Line Commutated Conversion (LCC), which limits the power controllability to two quadrant operation. However, the ratings of self-commutating switches such as the Insulated-Gate Bipolar Transistor (IGBT) and Integrated Gate-Commutated Thyristor (IGCT), are reaching levels that make the technology possible for very high power applications. This unique book reviews the present state and future prospects of self-commutating static power converters for applications requiring either